MEMC 98-3052 (2512.2) PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of Robert J. Falster Serial No. 10/038,084 Filed January 03, 2002 Confirmation No. 7363 Art Unit 2814

For SILICON ON INSULATOR STRUCTURE HAVING A LOW DEFECT DENSITY DEVICE LAYER AND A PROCESS FOR THE PREPARATION THEREOF

Examiner Anh D. Mai

June 28, 2004

AMENDMENT C

TO THE COMMISSIONER FOR PATENTS,

SIR:

In response to the Office action dated January 28, 2004, please consider the following remarks and arguments:

Remarks/Arguments begin on page 2 of this paper.

07/01/2004 AWONDAF1 00000073 191345 10038084

03 FC:1255 10.00 DA 2000.00 OP